2SD0662, 2SD0662B (2SD662, 2SD662B)

Silicon NPN epitaxial planar type

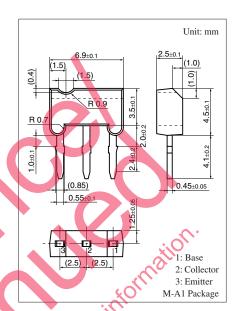
For high breakdown voltage general amplification

■ Features

- \bullet High collector-emitter voltage (Base open) V_{CEO}
- High transition frequency f_T
- M type package allowing easy automatic and manual insertion as well as stand-alone fixing to the printed circuit board.

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage	2SD0662	V_{CBO}	250	V
(Emitter open)	2SD0662B		400	
Collector-emitter voltage	2SD0662	V _{CEO}	200	V
(Base open)	2SD0662B		400	
Emitter-base voltage (Coll	V_{EBO}	5	V	
Collector current	I_{C}	70	mA	
Collector power dissipation		P _C	600	mW
Junction temperature		T_{j}	150	°C
Storage temperature	T_{stg}	-55 to +150	°C	



■ Electrical Characteristics $T_a = 25$ °C ± 3 °C

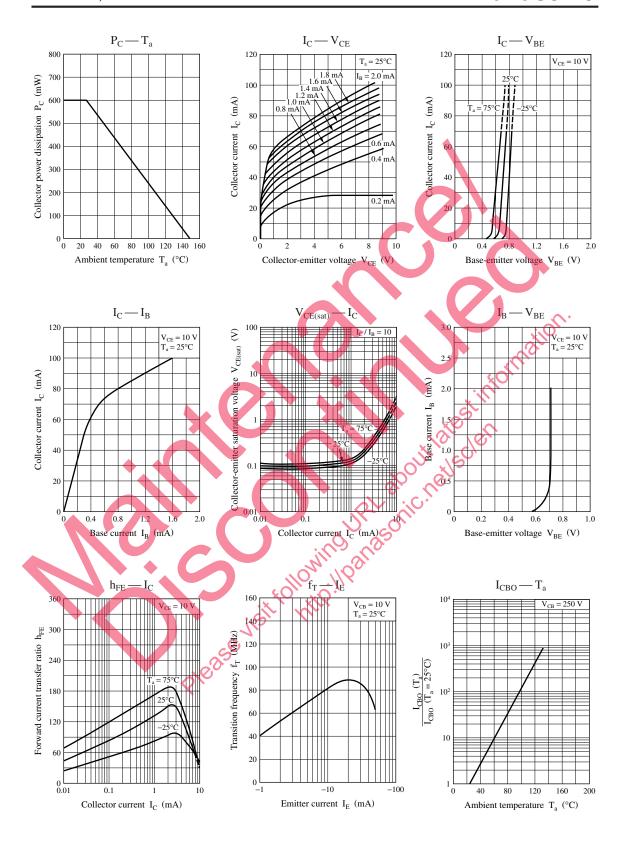
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage 2SD06	62 V _{CEO}	$I_C = 100 \mu A, I_B = 0$	200			V
(Base open) 2SD06	52B		400			
Emitter-base voltage (Collector oper	n) V _{EBO}	$I_E = 10 \mu\text{A}, I_C = 0$	5			V
Collector-emitter cutoff current (Base open	en) I _{CEO}	$V_{CE} = 100 \text{ V}, I_{B} = 0$			2	μΑ
Forward current transfer ratio	h _{FE} *	$V_{CE} = 10 \text{ V}, I_{C} = 5 \text{ mA}$	30		220	_
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C = 50 \text{ mA}, I_B = 5 \text{ mA}$			1.2	V
Transition frequency	f_{T}	$V_{CB} = 10 \text{ V}, I_E = -10 \text{ mA}, f = 200 \text{ M}$	Hz 50			MHz
Collector output capacitance	ccob	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$			10	pF
(Common base, input open circuite	d)					

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *: Rank classification

Rank	Р	Q	R	
h_{FE}	30 to 100	60 to 150	100 to 220	

Note) The part numbers in the parenthesis show conventional part number.



2 SJC00195BED

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